TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK1529

High-Power Amplifier Application

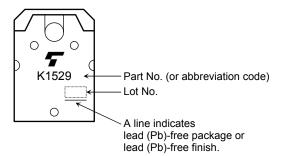
- High breakdown voltage $: V_{DSS} = 180V$
- High forward transfer admittance $|Y_{fs}| = 4.0 \text{ S (typ.)}$
- Complementary to 2SJ200

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage	V _{DSS}	180	V	
Gate-source voltage	V _{GSS}	±20	V	
Drain current (Note 1)	۱ _D	10	А	
Drain power dissipation (Tc = 25°C)	PD	120	W	
Channel temperature	Тc	150	°C	
Storage temperature range	T _{stg}	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



Weight: 4.6 g (typ.)

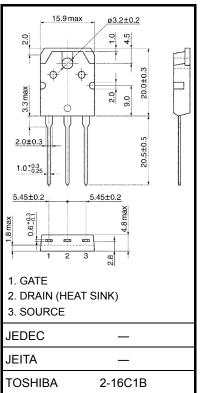
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain cut-off current	I _{DSS}	V _{DS} = 180 V, V _{GS} = 0	_	_	1.0	mA
Gate leakage current	I _{GSS}	V _{DS} = 0, V _{GS} = ±20 V	_	_	±0.5	μA
Drain-source breakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0	180	—	—	V
Drain-source saturation voltage	V _{DS (ON)}	I _D = 6 A, V _{GS} = 10 V	_	2.5	5.0	V
Gate-source cut-off voltage (Note 2)	V _{GS (OFF)}	V _{DS} = 10 V, I _D = 0.1 A	0.8	—	2.8	V
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 3 A	—	4.0	—	S
Input capacitance	C _{iss}	V_{DS} = 30 V, V_{GS} = 0, f = 1 MHz	_	700	_	
Output capacitance	C _{oss}	V _{DS} = 30 V, V _{GS} = 0, f = 1 MHz	—	150	—	pF
Reverse transfer capacitance	C _{rss}	V _{DD} = 30 V, V _{GS} = 0, f = 1 MHz	—	90	_	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: VGS (OFF) Classification 0: 0.8~1.6 Y: 1.4~2.8

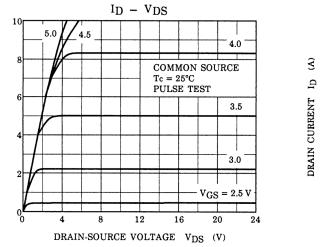
This transistor is an electrostatic-sensitive device. Please handle with caution.

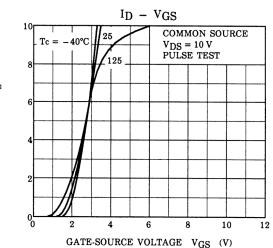


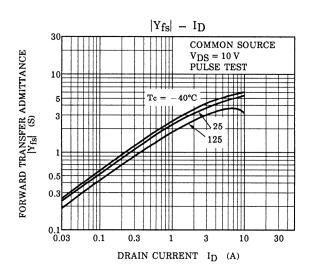
Unit: mm

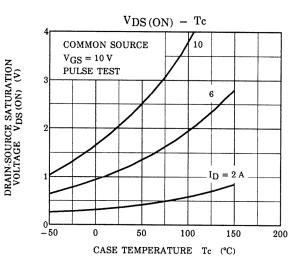
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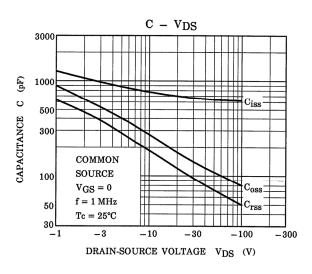


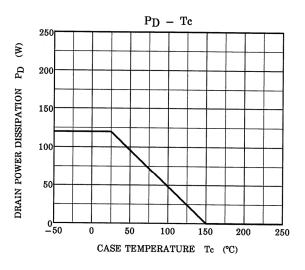




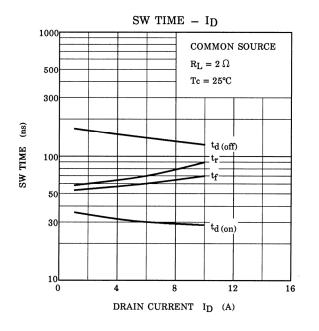


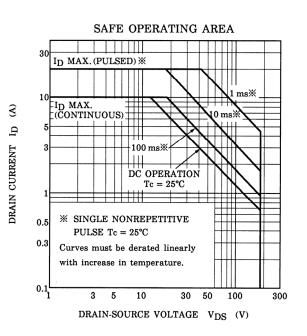




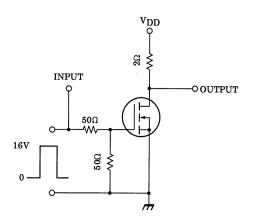


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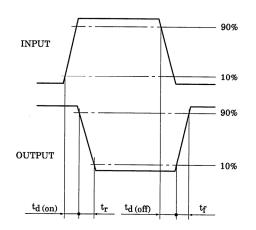




Switching Time Test Circuit



Waveforms



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